## NSN 5961-01-182-0811

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Inclosure Material: Metal Terminal Length: 0.440 inches Overall Height: 0.425 inches Internal Configuration: Junction contact Semiconductor Material: Silicon Voltage Rating In Volts Per Characteristic: 60.0 collector to emitter voltage/static/base open and 70.0 collector to emitter reverse voltage and 100.0 collector to base
0.440 inches Overall Height: 0.425 inches Internal Configuration: Junction contact Semiconductor Material: Silicon Voltage Rating In Volts Per Characteristic:
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Junction contact Semiconductor Material: Silicon Voltage Rating In Volts Per Characteristic:
Semiconductor Material: Silicon Voltage Rating In Volts Per Characteristic:
Silicon Voltage Rating In Volts Per Characteristic:
Voltage Rating In Volts Per Characteristic:
60.0 collector to emitter voltage/static/base open and 70.0 collector to emitter reverse voltage and 100.0 collector to base
voltage/static/emitter open and 7.0 emitter to base voltage, static, collector open
Current Rating Per Characteristic:
15.00 amperes source cutoff current
Power Rating Per Characteristic:
115.0 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0